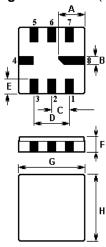


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The ACTR0016/916.5/QCC8C is a true one-port, surface-acoustic-wave (**SAW**) resonator in a surface-mount ceramic **QCC8C** case. It provides reliable, fundamental-mode, quartz frequency stabilization i.e. in transmitters or local oscillators operating at **916.500** MHz.

## 1.Package Dimension (QCC8C)

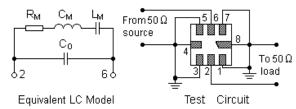


#### 2.

| Pin     | Configuration  |  |  |  |
|---------|----------------|--|--|--|
| 2       | Input / Output |  |  |  |
| 6       | Output / Input |  |  |  |
| 4,8     | Case Ground    |  |  |  |
| 1,3,5,7 | N C            |  |  |  |

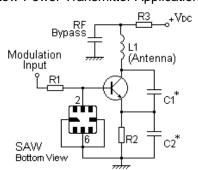
| Sign | Data (unit: mm) | Sign Data (unit: mi |      |
|------|-----------------|---------------------|------|
| Α    | 2.08            | Е                   | 1.2  |
| В    | 0.6             | F                   | 1.35 |
| С    | 1.27            | G                   | 5.0  |
| D    | 2.54            | Н                   | 5.0  |

## 3. Equivalent LC Model and Test Circuit

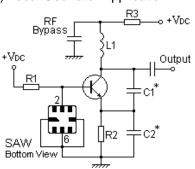


#### **4.Typical Application Circuits**

#### 1) Low-Power Transmitter Application



#### 2) Local Oscillator Application



Issue: 1 C1

Date: SEPT 04

In keeping with our ongoing policy of product evolvement and improvement, the above specification is subject to change without notice.

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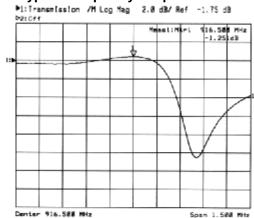
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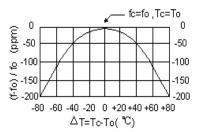


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## **5.Typical Frequency Response**



## **6.Temperature Characteristics**



The curve shown above accounts for resonator contribution only and does not include oscillator temperature characteristics.

#### 7.Performance

7-1.Maximum Ratings

| Rating                       |                | Value      | Unit |  |
|------------------------------|----------------|------------|------|--|
| CW RF Power Dissipation      | P              | 0          | dBm  |  |
| DC Voltage Between Terminals | $V_{ m DC}$    | ±30        | V    |  |
| Storage Temperature Range    | $T_{ m stg}$   | -40 to +85 | °C   |  |
| Operating Temperature Range  | T <sub>A</sub> | -10 to +60 | °C   |  |

#### 7-2. Electronic Characteristics

|  | Characteristic                       | Sym            | Minimum | Typical        | Maximum | Unit                |
|--|--------------------------------------|----------------|---------|----------------|---------|---------------------|
| Centre Frequency<br>(+25°C)                        | Absolute Frequency                   | f <sub>C</sub> | 916.350 |                | 916.650 | MHz                 |
|  | Tolerance from 916.500 MHz           | $\Delta f_{C}$ |         | ±150           |         | kHz                 |
| Insertion Loss                                     |                                      | ΙL             |         | 1.5            | 2.2     | dB                  |
| Quality Factor                                     | Unloaded Q                           | Q <sub>U</sub> |         | 10,020         |         |                     |
|  | 50 Ω Loaded Q                        | $Q_L$          |         | 1,500          |         |                     |
| Temperature<br>Stability                           | Turnover Temperature                 | T <sub>0</sub> | 25      |                | 55      | °C                  |
|  | Turnover Frequency                   | $f_0$          |         | f <sub>C</sub> |         | kHz                 |
|  | Frequency Temperature Coefficient    | FTC            |         | 0.032          |         | ppm/°C <sup>2</sup> |
| Frequency Aging                                    | Absolute Value during the First Year | fA             |         | ≤10            |         | ppm/yr              |
| DC Insulation Resistance Between Any Two Terminals |                                      |                | 1.0     |                |         | МΩ                  |
| RF Equivalent<br>RLC Model                         | Motional Resistance                  | $R_{M}$        |         | 19             | 29      | Ω                   |
|  | Motional Inductance                  | L <sub>M</sub> |         | 31.0132        |         | μН                  |
|  | Motional Capacitance                 | См             |         | 0.9734         |         | fF                  |
|  | Shunt Static Capacitance             | C <sub>0</sub> | 1.8     | 2.1            | 2.4     | pF                  |

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# **i** CAUTION: Electrostatic Sensitive Device. Observe precautions for handling!

- 1. The centre frequency,  $f_C$ , is measured at the minimum IL point with the resonator in the 50  $\Omega$  test system.
- 2. Unless noted otherwise, case temperature  $T_C = +25^{\circ}C \pm 2^{\circ}C$ .
- Frequency aging is the change in f<sub>C</sub> with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- 4. Turnover temperature,  $T_0$ , is the temperature of maximum (or turnover) frequency,  $f_0$ . The nominal frequency at any case temperature,  $T_0$ , may be calculated from:  $f = f_0 [1 FTC (T_0 T_0)^2]$ .
- 5. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C<sub>0</sub> is the measured static (non-motional) capacitance between the two terminals. The measurement includes case parasitic capacitance.
- Derived mathematically from one or more of the following directly measured parameters: f<sub>C</sub>, IL, 3 dB bandwidth, f<sub>C</sub> versus T<sub>C</sub>, and C<sub>0</sub>.
- The specifications of this device are based on the test circuit shown above and subject to change or obsolescence without notice.
- 8. Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 9. Our liability is only assumed for the Surface Acoustic Wave (SAW) component(s) per se, not for applications, processes and circuits implemented within components or assemblies.

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